

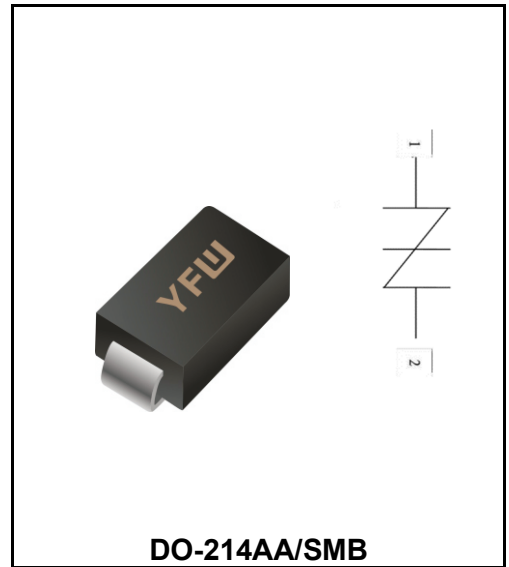
Thyristors Surge Protection Device

Features

- ◆ For surface mounted applications to optimize board space
- ◆ Low profile package
- ◆ Bidirectional crowbar protection
- ◆ Low leakage current : $I = 5\mu A$ max
- ◆ Low on-state voltage
- ◆ Solid-state silicon technology

Application

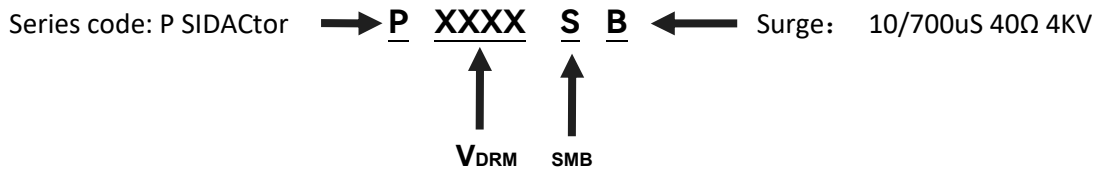
- ◆ TIA-968-A/B
- ◆ ITU K.20/21 Enhanced Level*
- ◆ ITU K.20/21 Basic Level*
- ◆ GR 1089 Inter-building*
- ◆ GR 1089 Intra-building
- ◆ IEC 61000-4-5 2nd edition
- ◆ YD/T 1082 YD/T 993 YD/T 950



Absolute Maximum Ratings (TA=25°C, RH=45%-75%, unless otherwise noted)

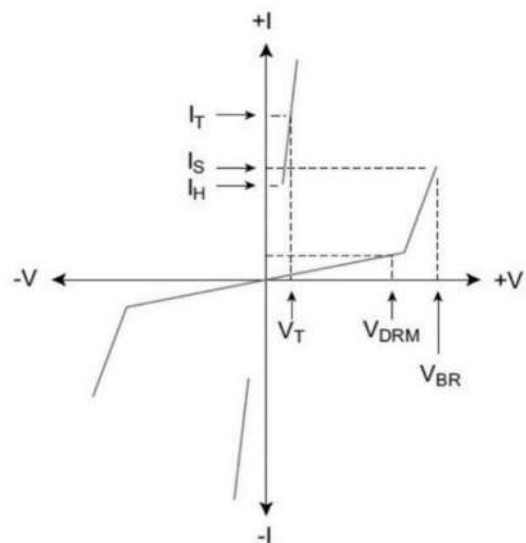
Parameter	Symbol	Value	Unit
Storage temperature range	Tstg	-60 to +150	°C
Operating junction temperature range	Tj	-40 to +150	°C

Part Number Code



Electrical Parameters & V-I Curve

Symbol	Parameter
V _{DRM}	Peak off-state voltage
I _{DRM}	Off-state current
V _S	Switching voltage
I _S	Switching current
V _T	On-state voltage
I _T	On-state current
I _H	Holding current
C _O	Off-state capacitance



Electrical Characteristics (TA=25°C)

Type	V _{DRM}	I _{DRM}	V _S	I _S	V _T	I _T	C _O	I _H
	Min.	Max.	Max.	Max.	Max.		Typ.	Min.
	V	uA	V	mA	V	A	pF	mA
P0080SB	6	5	25	800	4	2.2	80	20
P0300SB	25	5	40	800	4	2.2	100	50
P0640SB	58	5	77	800	4	2.2	80	100
P0720SB	65	5	88	800	4	2.2	80	100
P0900SB	75	5	98	800	4	2.2	75	100
P1100SB	90	5	130	800	4	2.2	75	100
P1300SB	120	5	160	800	4	2.2	75	100
P1500SB	140	5	180	800	4	2.2	70	100
P1800SB	170	5	220	800	4	2.2	70	100
P2000SB	180	5	220	800	4	2.2	70	100
P2300SB	190	5	260	800	4	2.2	65	100
P2600SB	220	5	300	800	4	2.2	65	100
P3100SB	275	5	350	800	4	2.2	60	100
P3500SB	320	5	400	800	4	2.2	60	100
P4000SB	360	5	460	800	4	2.2	60	100
P4200SB	390	5	500	800	4	2.2	60	100
P4500SB	420	5	540	800	4	2.2	60	100
P5000SB	500	5	600	800	4	2.2	60	100

Notes:

- All measurements are made at an ambient temperature of 25°C. IPP applies to -40°C through +85°C temperature range.
- Off-state capacitance (CO) is measured at 1 MHz with a 2 V bias and is typical value.

Ratings And V-I Characteristics Curves (TA=25°C, unless otherwise noted)

FIG.1: tr × td pulse waveform

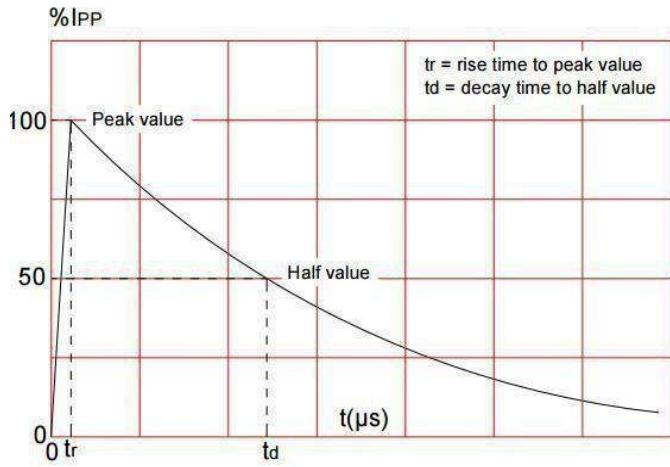


FIG.2: Reflow condition

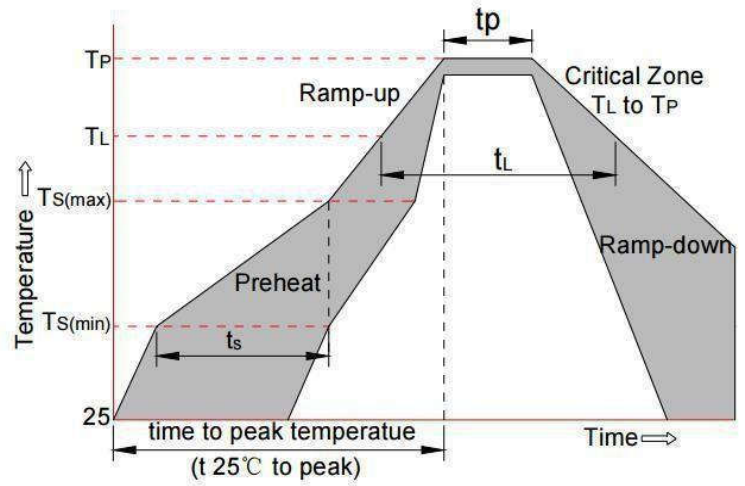


FIG.3: Normalized Vs change vs. junction temperature

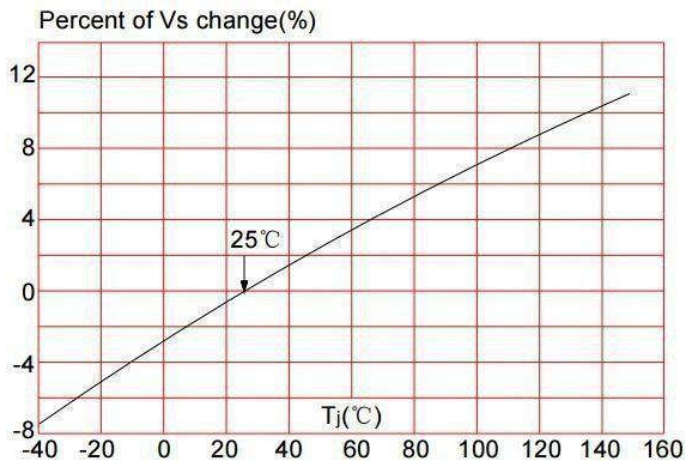
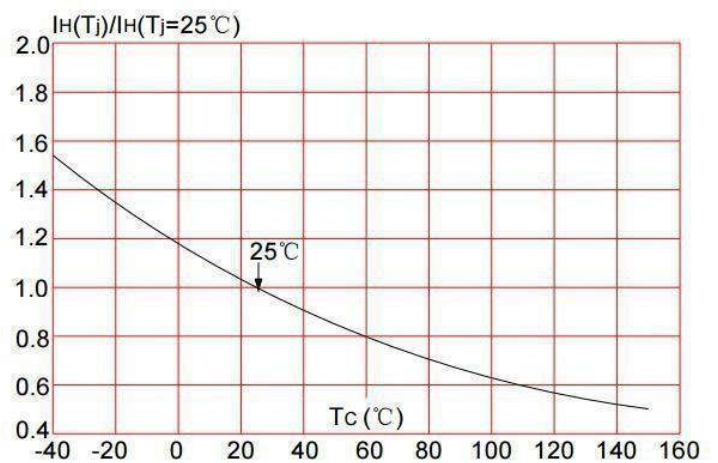
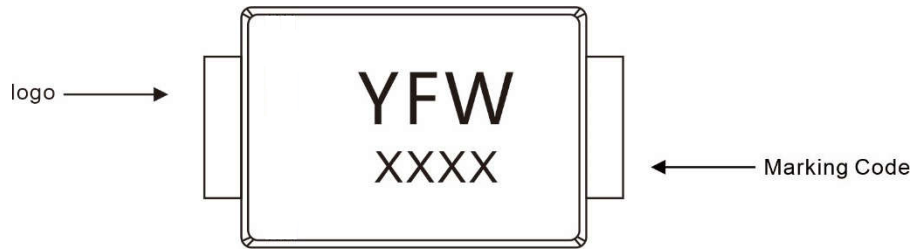


FIG.4: Normalized DC holding current vs. case temperature



Marking Diagram



Ordering information

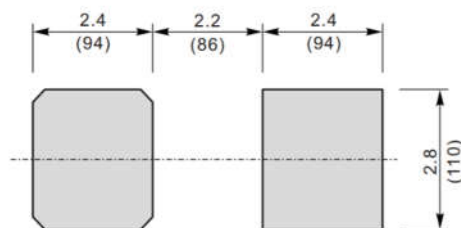
Package	Packing Description	Packing Quantity
DO-214AA SMB	Tape/Reel, 13" reel	3000PCS/Reel 30000PCS/Carion

Package Dimensions

DO-214AA SMB

Dim.	Millimeter(mm)		mil	
	Min.	Max.	Min.	Max.
A	2.13	2.44	84	96
E	4.06	4.70	160	185
D	3.3	3.94	130	155
E ₁	5.08	5.59	200	220
A ₁	0.05	0.20	2.0	7.9
L	0.8	1.5	32	59
C	0.152	0.305	6	12
b	1.9	2.2	75	87

The recommended mounting pad size



Unit : $\frac{\text{mm}}{\text{(mil)}}$

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